

Single Supply, Rail-to-Rail Output Quad Operational Amplifier

■GENERAL DESCRIPTION

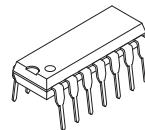
NJM2747 is a low noise Rail-to-Rail Output quad operational amplifier.

Rail-to-Rail Output function provides wide dynamic range, is from ground to power supply level. And Input range rails from ground level.

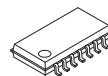
It is suitable for audio section of portable sets, PCs and any General-purpose applications.

NJM2747SCC is available in the small PCSP package, which saves space on printed circuit boards and suitable for small portable devices.

■PACKAGE OUTLINE



NJM2747D



NJM2747M



NJM2747E



NJM2747V

■ FEATURES

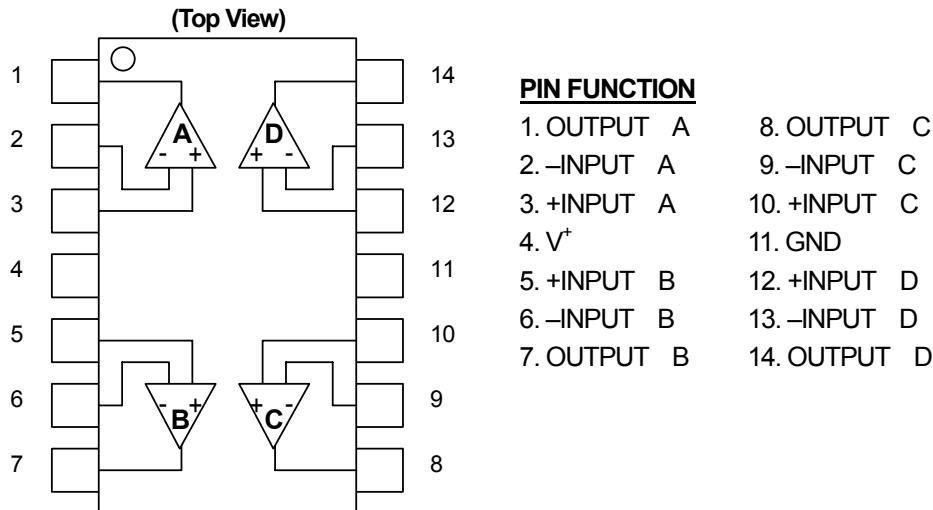
- Operating Voltage 2.5V to 14V
- Rail-to-Rail Output $V_{OH} \geq 4.9V$ Typ. (at $V^+ = 5V$, $R_L = 5k\Omega$)
 $V_{OL} \leq 0.1V$ Typ. (at $V^+ = 5V$, $R_L = 5k\Omega$)
1mV Typ.
- Offset Voltage 3.5V/ μ s Typ.
- Slew Rate 0.001% Typ. (at $V^+ = 5V$, $f = 1kHz$)
10nV/ \sqrt{Hz} Typ. (at $f = 1kHz$)
- Low Distortion
- Low Input Voltage Noise
- Bipolar Technology
- Package Outline

NJM2747D	DIP14 (Lead insertion type)
NJM2747E	EMP14 (Surface mount type)
NJM2747M	DMP14 (Surface mount type)
NJM2747V	SSOP14 (Surface mount type)
NJM2747SCC	PCSP20-CC (Surface mount type very small size package)

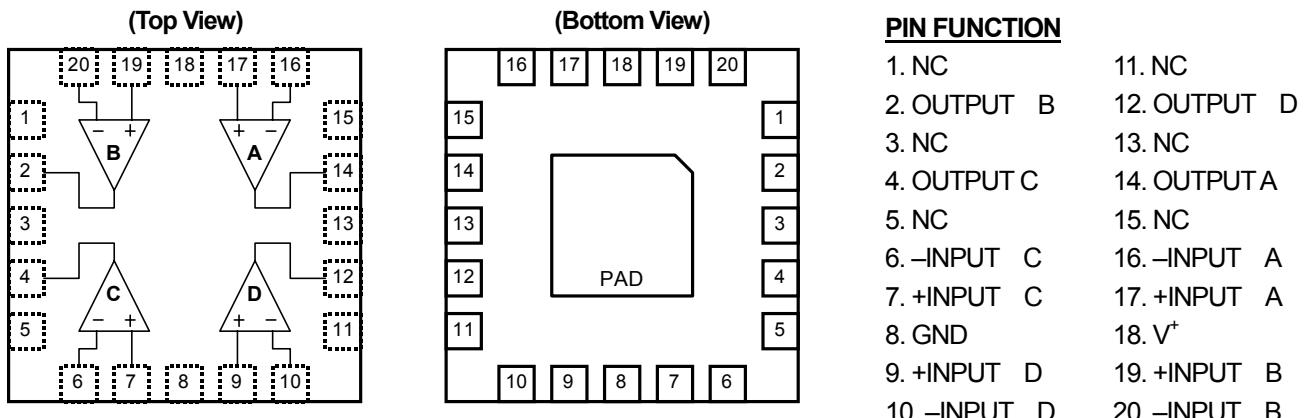
NJM2747

■ PIN CONFIGURATION

- NJM2747D, NJM2747E, NJM2747M, NJM2747V



- NJM2747SCC



(Note1) The NC pin and the PAD should connect with a GND terminal.

(Note2) The NC pin is electrically not connected to the die in a package.

(Note3) The PAD is electrically not connected to the backside of the die. The PAD cannot be used as GND pin.

(Note4) NJM2747SCC package size is [W: 2.7mm, D: 2.7mm, H: 0.8mm]. Please confirm the size information by a package specification.

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	15	V
Differential Input Voltage Range	V _{ID}	±15 (Note5)	V
Common Mode Input Voltage Range	V _{ICM}	0 to 15 (Note5)	V
Power Dissipation	P _D	870 [DIP14]	mW
		720 [EMP14] (Note6), 450 [DMP14] (Note6), 420 [SSOP14] (Note6), 380 [PCSP20-CC] (Note6),	
		1200 [EMP14] (Note7), 560 [DMP14] (Note7), 520 [SSOP14] (Note7), 550 [PCSP20-CC] (Note7),	
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-50 to +125	°C

(Note5) For supply voltage less than 15V, the absolute maximum input voltage is equal to the supply voltage.

(Note6) On the PCB "EIA/JEDEC (76.2×114.3×1.6mm, two layers, FR-4)"

(Note7) On the PCB "EIA/JEDEC (76.2×114.3×1.6mm, four layers, FR-4)"

(Note8) Do not exceed "Power dissipation: PD" in which power dissipation in IC is shown by the absolute maximum rating.

Refer to following Figure 1A and Figure 1B for a permissible loss when ambient temperature (Ta) is Ta≥25°C.

Figure 1A : Power Dissipation – Ambient Temperature

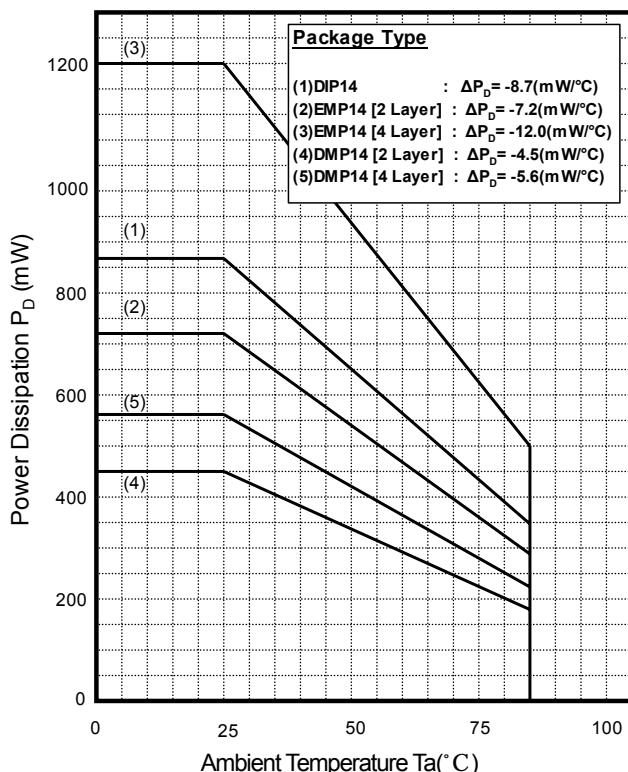
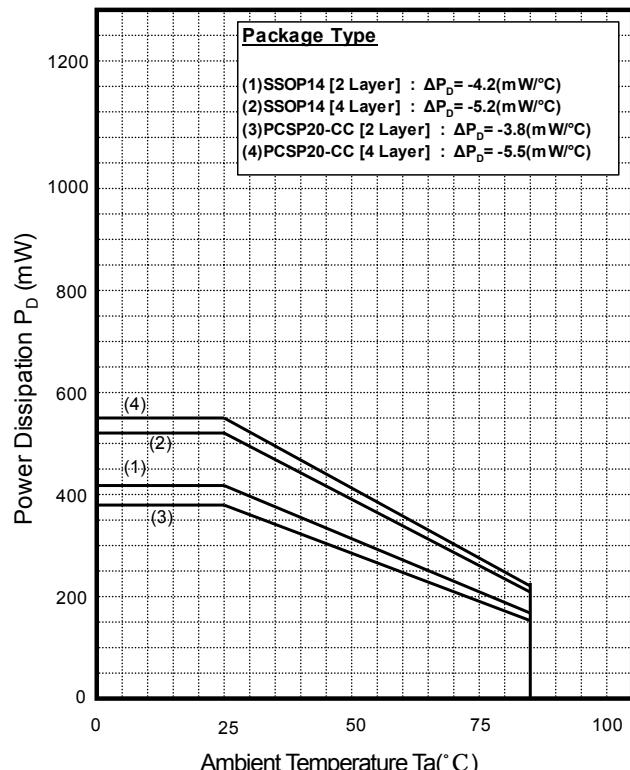


Figure 1B : Power Dissipation – Ambient Temperature



■ OPERATING VOLTAGE (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	2.5 to 14 (Note8)	V

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■ ELECTRICAL CHARACTERISTICS

•DC CHARACTERISTICS ($V^+=5V, Ta=25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I_{CC}	$R_L=\infty, V_{IN}=2.5V,$ No Signal Apply	-	8	11	mA
Input Offset Voltage	V_{IO}	$R_S \leq 10k\Omega$	-	1	6	mV
Input Bias Current	I_B		-	100	350	nA
Input Offset Current	I_{IO}		-	5	100	nA
Large Signal Voltage Gain	A_V	$R_L \geq 10k\Omega$ to 2.5V, $V_o=0.5V$ to 4.5V	65	85	-	dB
Common Mode Rejection Ratio	CMR	$0V \leq V_{CM} \leq 4V$	60	75	-	dB
Supply Voltage Rejection Ratio	SVR	$V^+=2.5V$ to 14V	60	80	-	dB
Output Voltage	V_{OH}	$R_L=5k\Omega$ to 2.5V	4.75	4.9	-	V
	V_{OL}	$R_L=5k\Omega$ to 2.5V	-	0.1	0.25	V
Input Common Mode Voltage Range	V_{ICM}	$CMR \geq 60dB$	0	-	4	V

•AC CHARACTERISTICS ($V^+=5V, Ta=25^\circ C$)

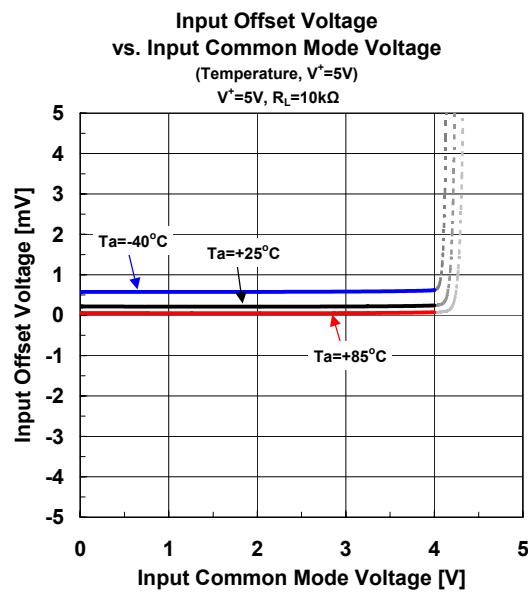
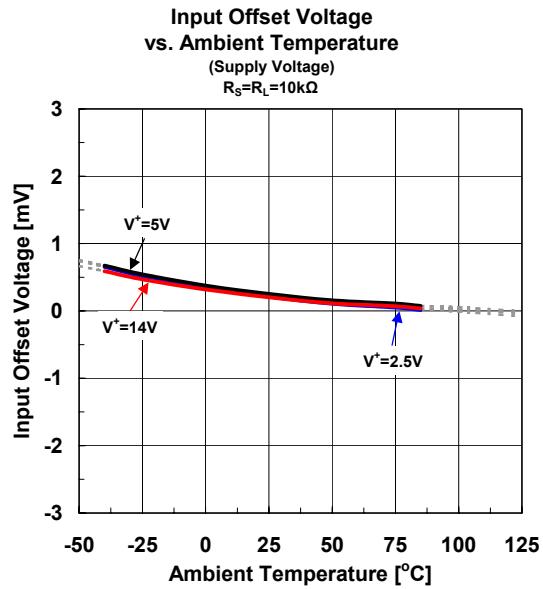
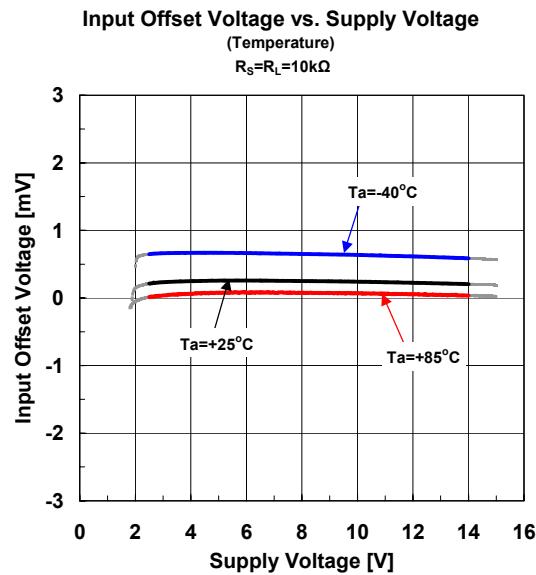
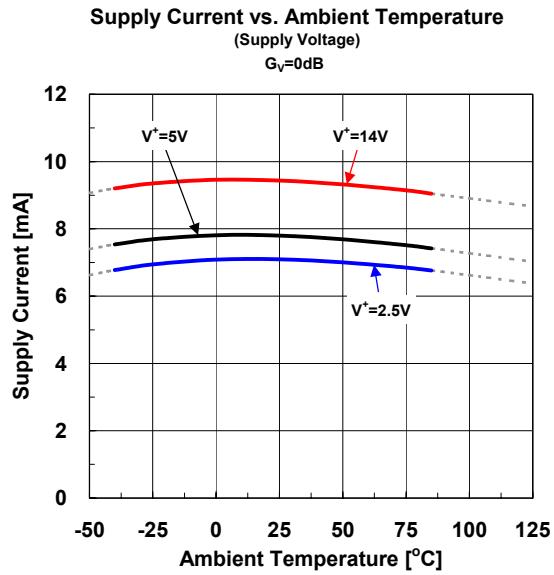
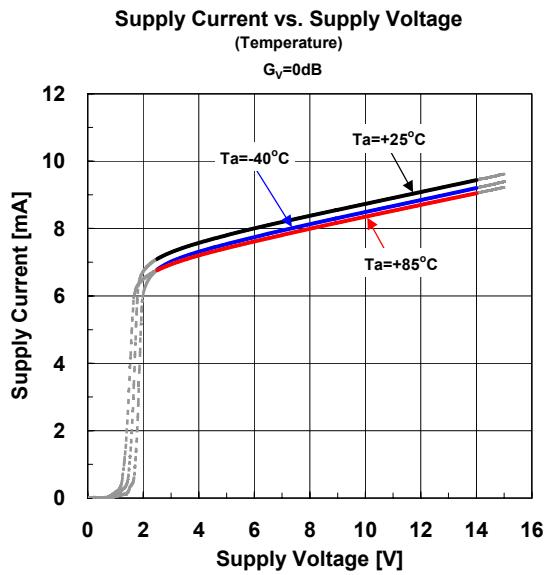
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Bandwidth	GB	$f=10kHz$	-	10	-	MHz
Phase Margin	Φ_M	$R_L=10k\Omega, C_L=10pF$	-	75	-	Deg
Equivalent Input Noise Voltage	V_{NI}	$f=1kHz, V_{CM}=2.5V$	-	10	-	nV/ \sqrt{Hz}
Total Harmonic Distortion	THD	$f=1kHz, A_V=+2$ $R_L=10k\Omega$ to 2.5V, $V_o=1.5V_{rms}$	-	0.001	-	%
Amp to Amp Separation	CS	$f=1kHz$ $R_L=10k\Omega$ to 2.5V, $V_o=1.5V_{rms}$	-	120	-	dB

•AC CHARACTERISTICS ($V^+=5V, Ta=25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	(Note 9), $A_V=1, V_{IN}=2V_{pp}$ $R_L=10k\Omega$ to 2.5V $C_L=10pF$ to 2.5V	-	3.5	-	V/ μs

(Note 9) Number specified is the slower of the positive and negative slew rates.

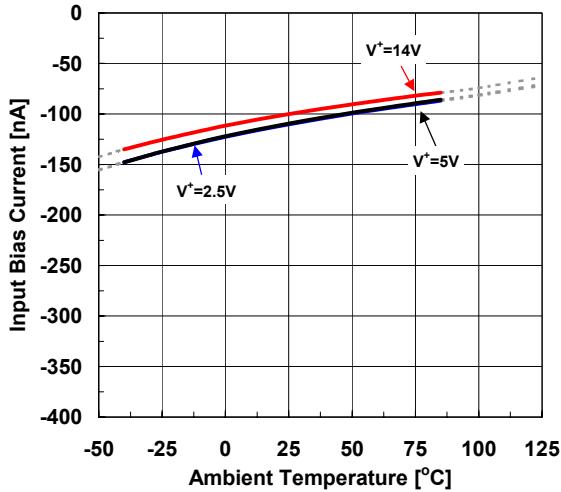
■ TYPICAL CHARACTERISTICS



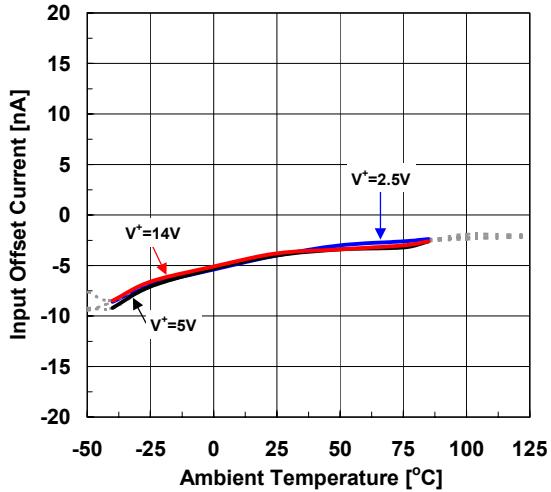
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■ TYPICAL CHARACTERISTICS

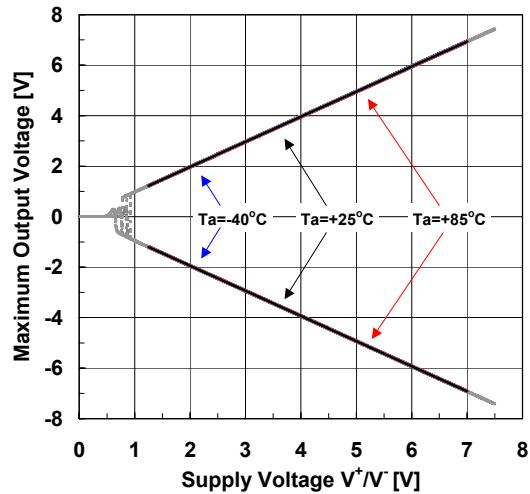
Input Bias Current vs. Ambient Temperature
(Supply Voltage)
 $R_L=10\text{k}\Omega$



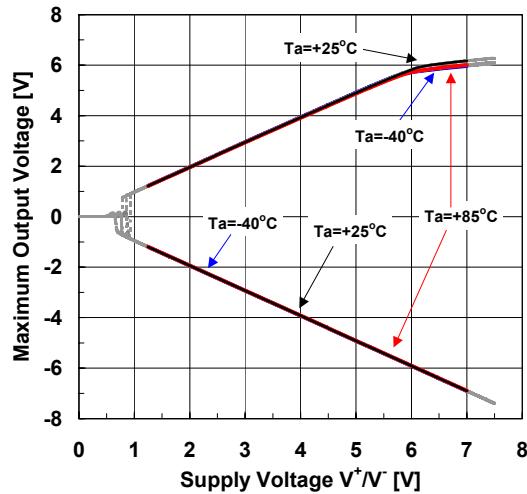
Input Offset Current vs. Ambient Temperature (Supply Voltage)
 $R_L=10\text{k}\Omega$



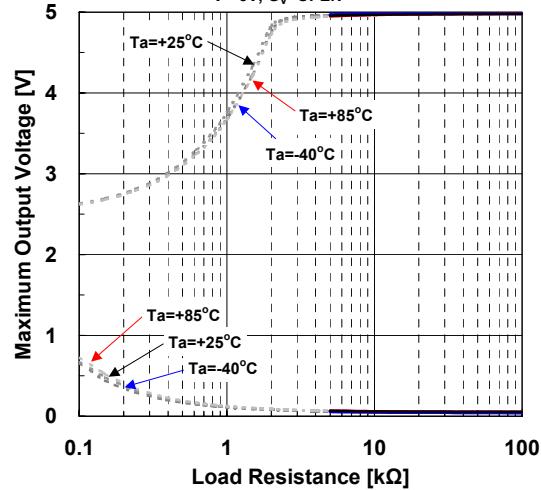
Maximum Output Voltage vs. Supply Voltage
(Temperature, $R_L=10\text{k}\Omega$)
 $G_V=\text{OPEN}$, $R_L=10\text{k}\Omega$



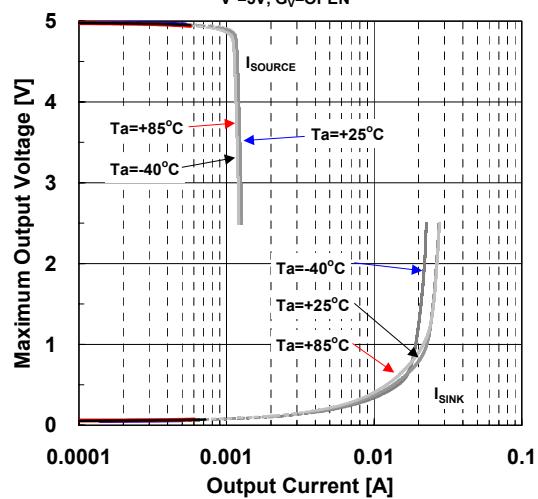
Maximum Output Voltage vs. Supply Voltage
(Temperature, $R_L=5\text{k}\Omega$)
 $G_V=\text{OPEN}$, $R_L=10\text{k}\Omega$



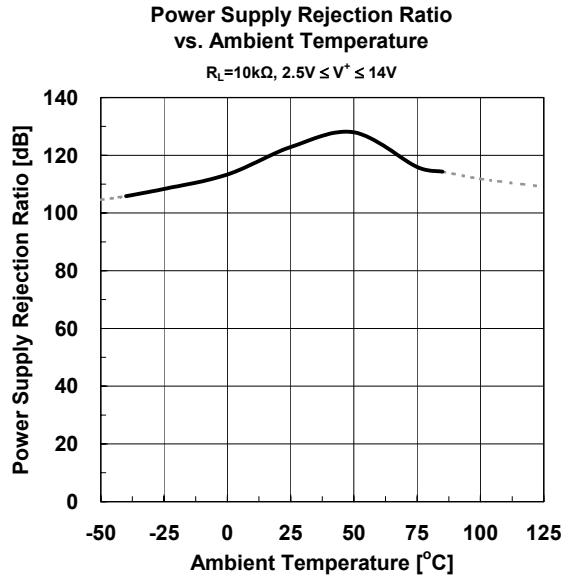
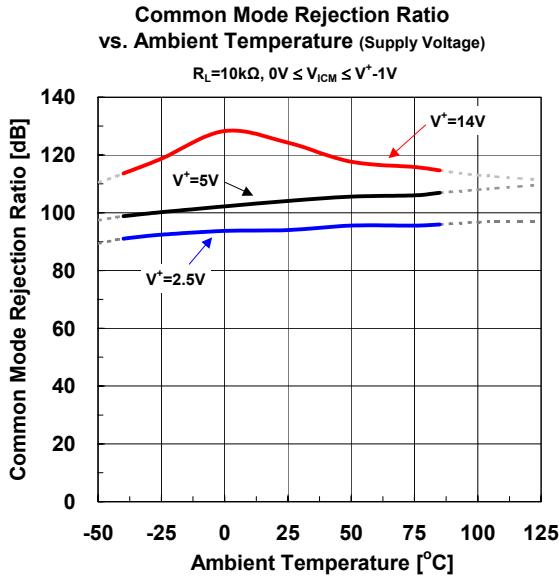
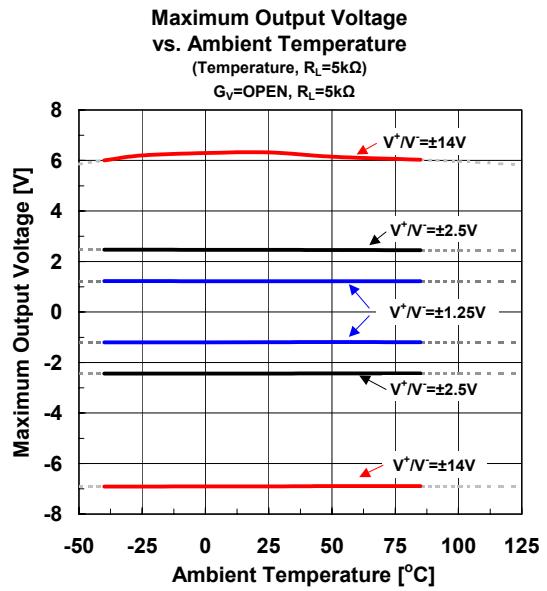
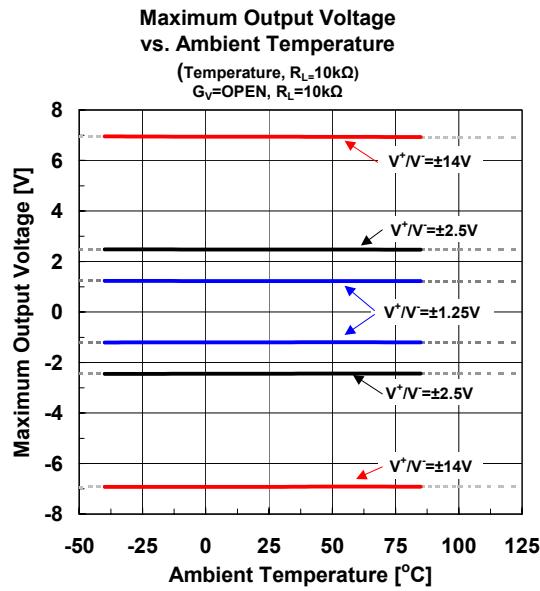
Maximum Output Voltage vs. Load Resistance
(Temperature, $V^+=5\text{V}$)
 $V^+=5\text{V}$, $G_V=\text{OPEN}$



Maximum Output Voltage vs. Output Current
(Temperature, $V^+=5\text{V}$)
 $V^+=5\text{V}$, $G_V=\text{OPEN}$

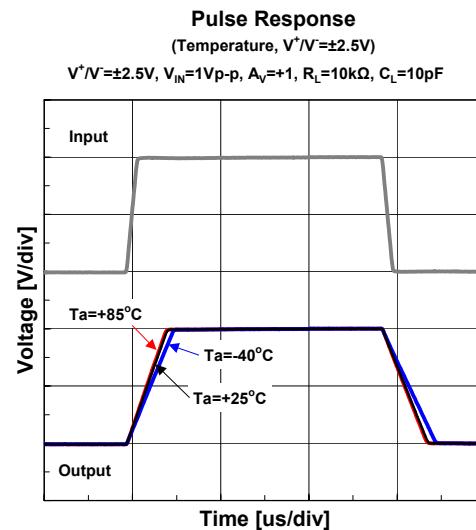
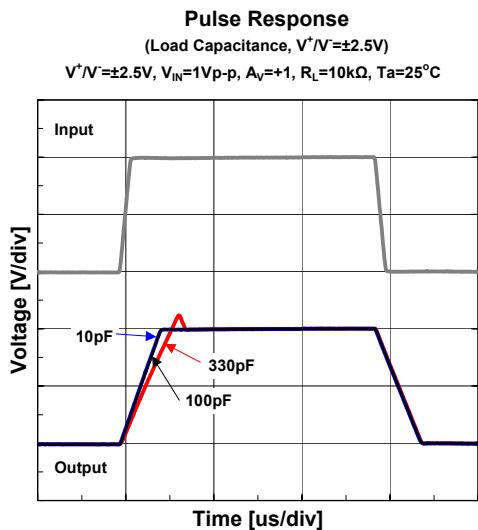
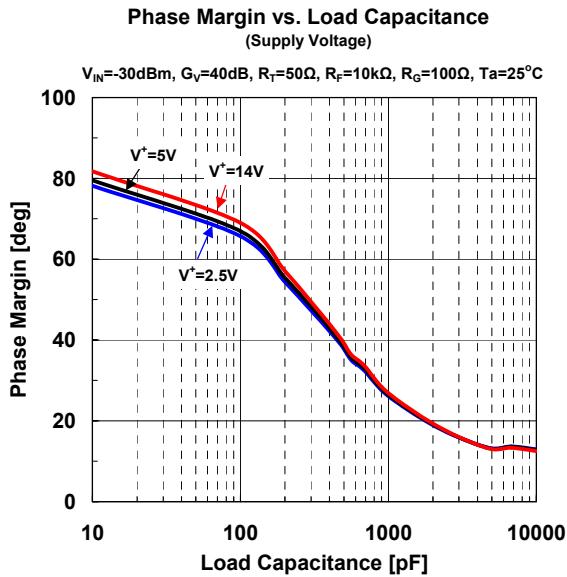
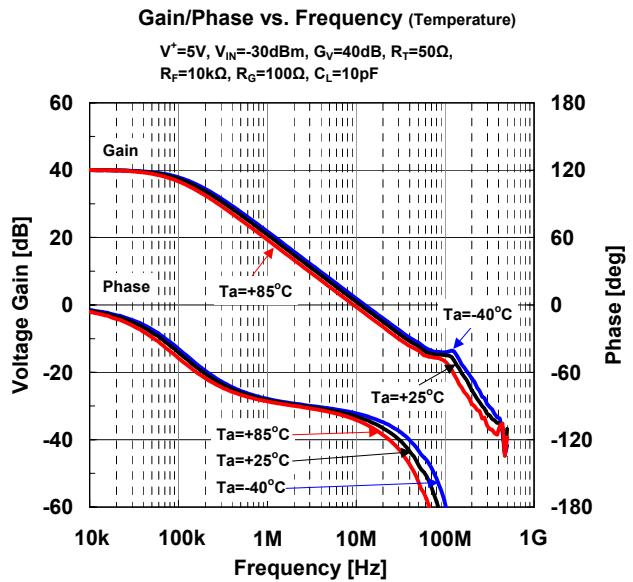
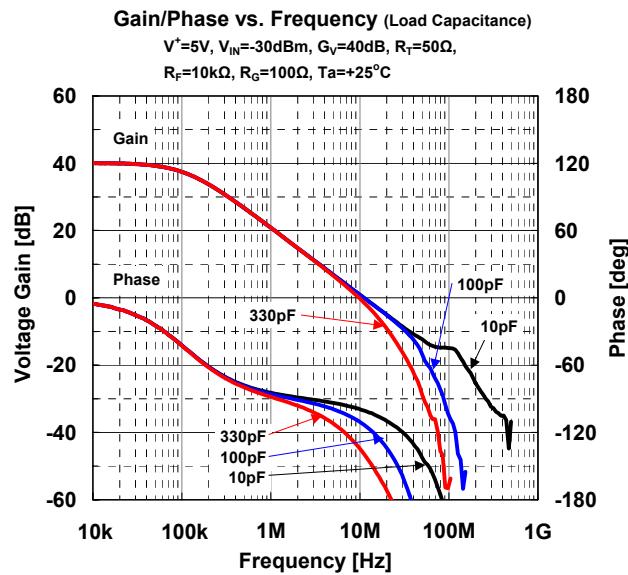


■ TYPICAL CHARACTERISTICS



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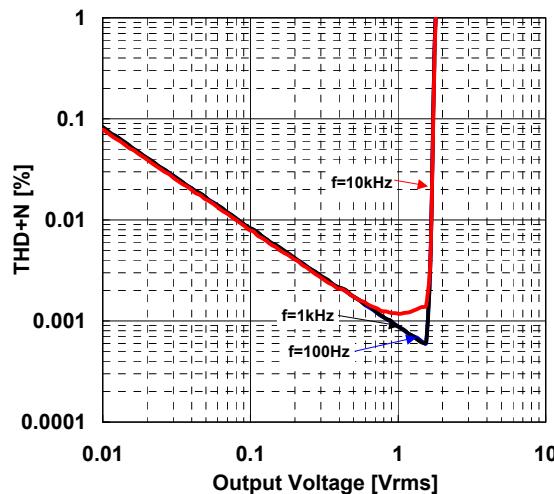
■ TYPICAL CHARACTERISTICS



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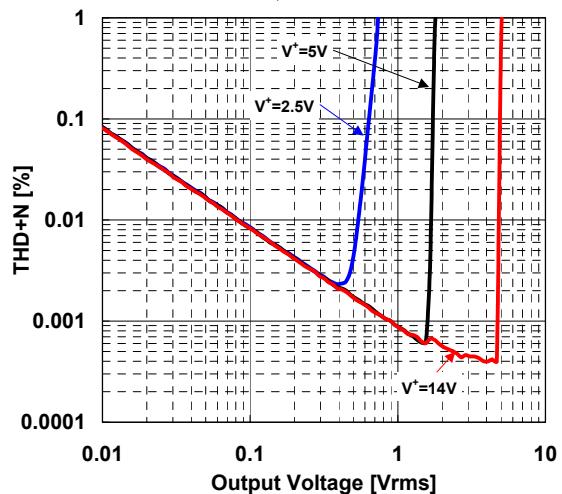
THD+N vs. Output Voltage (Frequency)

$V^+ = 5V$, $A_V = +2$, $R_S = 600\Omega$, $R_F = 5k\Omega$, $R_G = 5k\Omega$,
 BW = 10Hz~80kHz, $T_a = 25^\circ C$



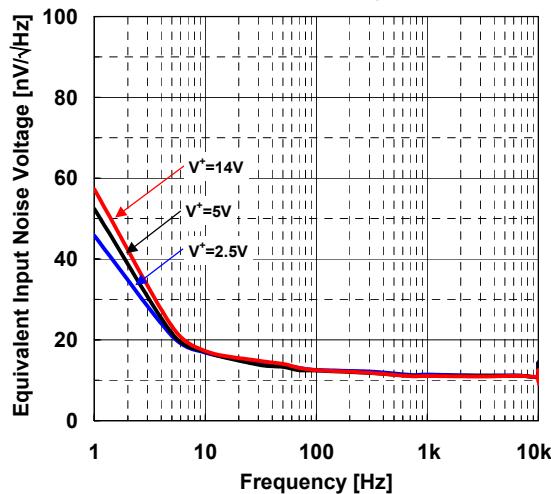
THD+N vs. Output Voltage (Supply Voltage)

$f = 1kHz$, $A_V = +2$, $R_S = 600\Omega$, $R_F = 5k\Omega$, $R_G = 5k\Omega$,
 BW = 10Hz~80kHz, $T_a = 25^\circ C$



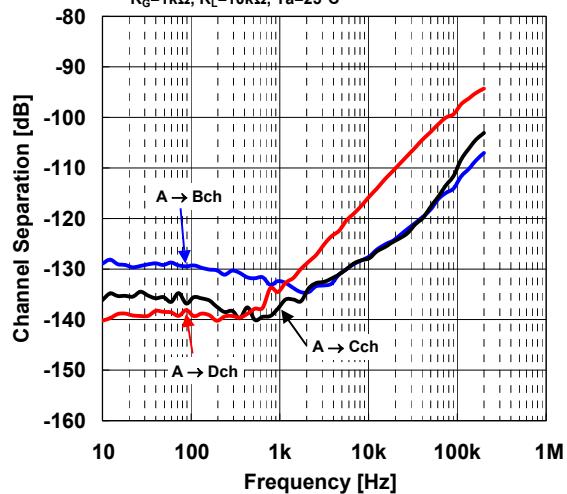
Equivalent Input Noise Voltage vs. Frequency (Supply Voltage)

$G_V = 60dB$, $R_T = 600\Omega$, $R_F = 100k\Omega$, $R_G = 100\Omega$, $T_a = 25^\circ C$



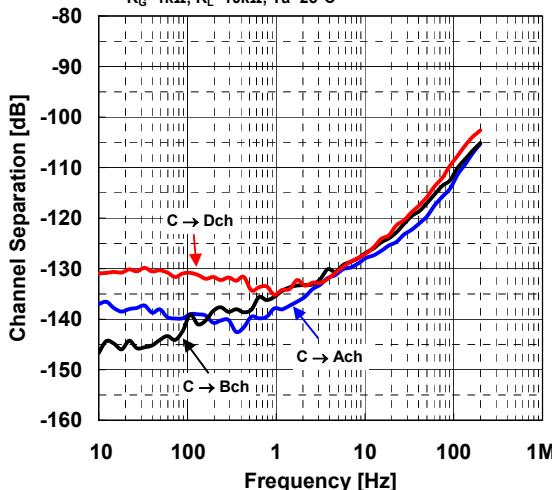
Channel Separation vs. Frequency

$V^+ = 5V$, A_{ch} Input, $V_O = 1.5V$ rms, $G_V = 40dB$, $R_F = 100k\Omega$,
 $R_G = 1k\Omega$, $R_L = 10k\Omega$, $T_a = 25^\circ C$



Channel Separation vs. Frequency

$V^+ = 5V$, C_{ch} Input, $V_O = 1.5V$ rms, $G_V = 40dB$, $R_F = 100k\Omega$,
 $R_G = 1k\Omega$, $R_L = 10k\Omega$, $T_a = 25^\circ C$



■ MEMO

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